

## ESD9B\*\*

**1-Line, Bi-directional, Normal-Capacitance,  
Transient Voltage Suppressors**

[Http://www.willsemi.com](http://www.willsemi.com)

### Descriptions

The ESD9B\*\* series are Bi-directional transient voltage suppressors (TVS) to protect sensitive electronic components from electrostatic discharge (ESD). It is particularly well-suited for cellular phones, PMP, MID, PDA, digital cameras and other electronic equipments.

The ESD9B\*\* series are safely dissipating ESD strikes to meet the ESD immunity testing of IEC61000-4-2 level 4.

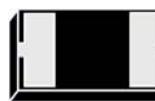
The ESD9B\*\* series are available in a FBP-02C, SOD-923 and DFN1006 package with Pb-free.



**FBP-02C**



**SOD-923**



**DFN1006**



**Pin configuration (Top view)**

### Features

- Working voltage : 5V
- Peak power (tp=8/20us) : 85W Max.
- Peak current (tp=8/20us) : 6.5A Max.
- Transient protection IEC61000-4-2 : ±30kV air  
: ±30kV contact
- Low clamping voltage
- Low leakage current
- Small package



**FBP-02C**



**SOD-923**



**DFN1006**

\* = Month (A~Z)

B = Device code

9C = Device code

Marking

### Applications

- Cell phone
- PMP
- MID
- PDA
- Digital camera
- Other electronics equipments

### Order information

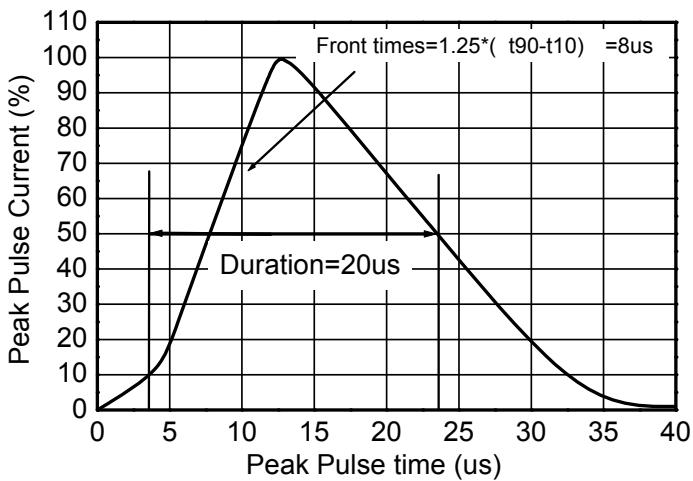
Device	Package	Shipping
ESD9B5V-2/TR	FBP-02C	10000/Tape&Reel
ESD9B5VD-2/TR	SOD-923	5000/Tape&Reel
ESD9N5B-2/TR	DFN1006	5000/Tape&Reel

**Absolute maximum ratings**

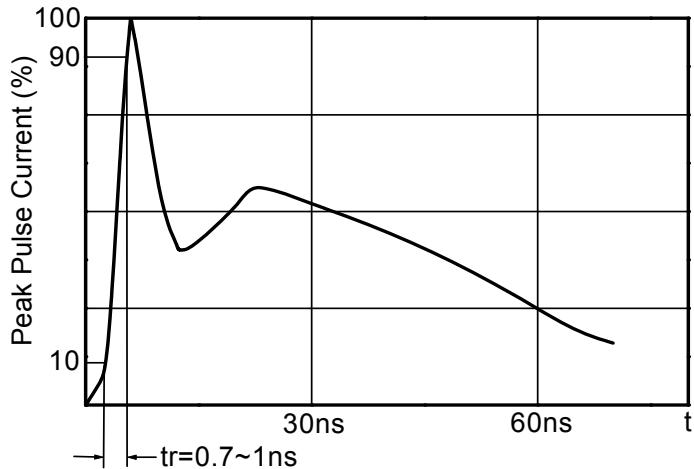
Parameter	Symbol	Rating	Unit
Peak pulse power (tp=8/20us)	Ppk	85	W
Peak pulse current (tp=8/20us)	Ipp	6.5	A
ESD voltage IEC61000-4-2 air	V <sub>ESD</sub>	±30	kV
ESD voltage IEC61000-4-2 contact		±30	
Operation junction temperature	T <sub>J</sub>	125	°C
Lead temperature	T <sub>L</sub>	260	°C
Storage temperature	Tsg	-55~150	°C

**Electronics characteristics (Ta=25 °C, unless otherwise noted)**

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reveres maximum working voltage	V <sub>RWM</sub>				5.0	V
Reveres leakage current	I <sub>R</sub>	V <sub>RWM</sub> =5V			1.0	uA
Reveres breakdown voltage	V <sub>BR</sub>	I <sub>T</sub> =1mA	5.6	7.5	8.2	V
Forward voltage	V <sub>F</sub>	I <sub>F</sub> =1mA	5.6	7.5	8.2	V
Clamping voltage	V <sub>C</sub>	I <sub>pp</sub> =1A tp=8/20us			9	V
		I <sub>pp</sub> =6.5A tp=8/20us			13	V
Junction capacitance	C	F=1MHz, V <sub>R</sub> =0V		20	35	pF

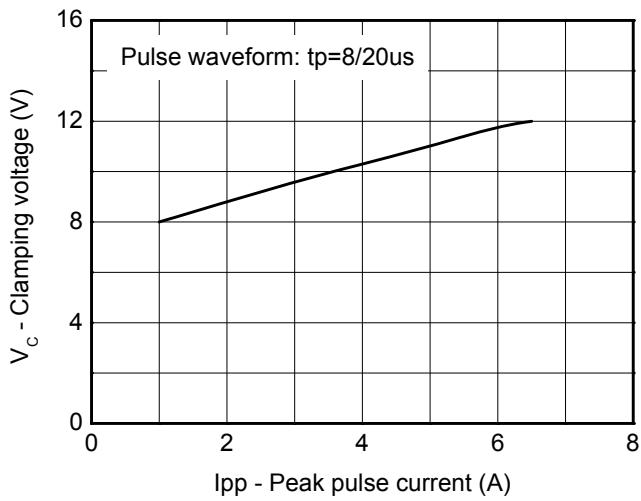


8/20μs waveform

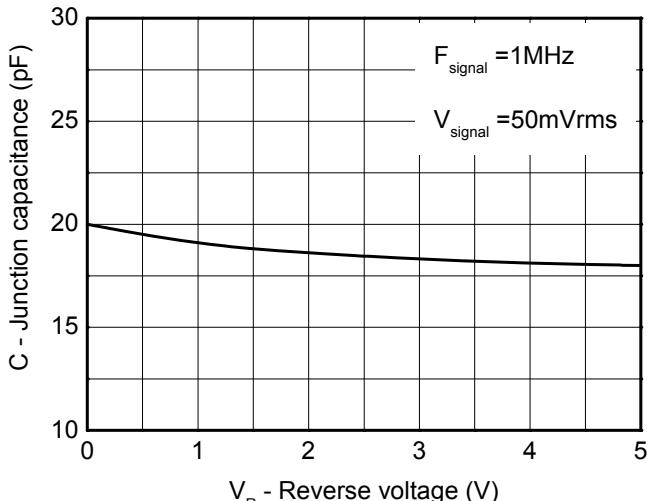


IEC61000-4-2 waveform

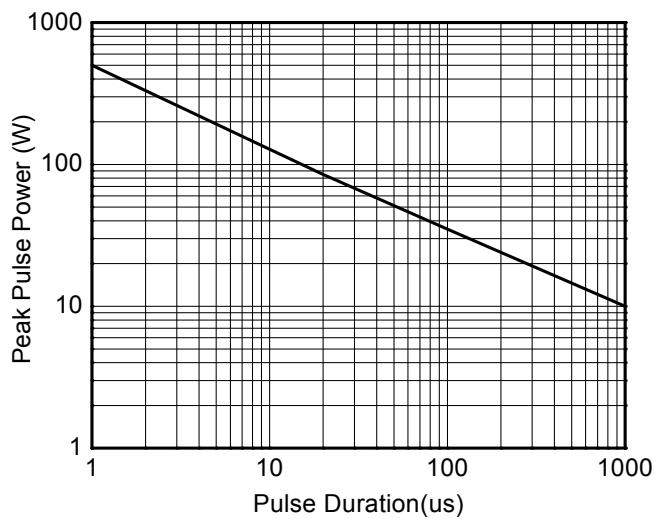
**Typical characteristics ( $T_a=25^\circ\text{C}$ , unless otherwise noted)**



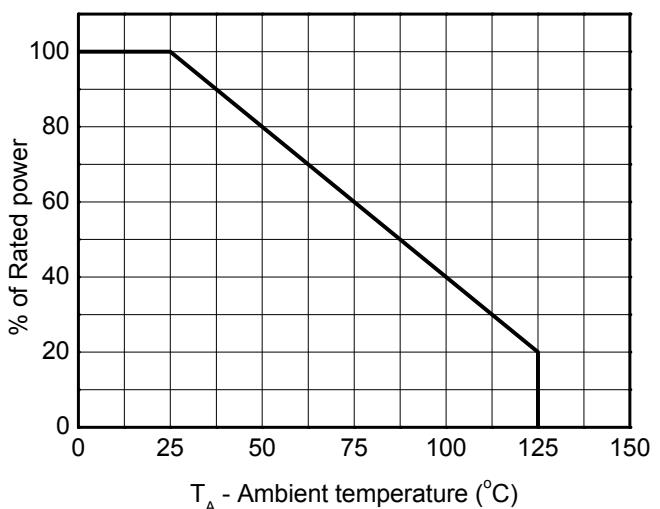
**Clamping voltage vs. Peak pulse current**



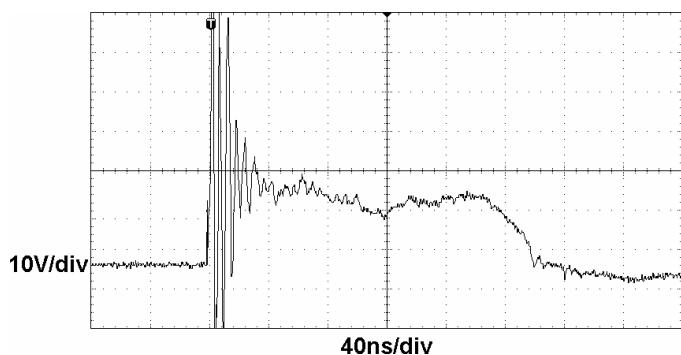
**Capacitance vs. Reveres voltage**



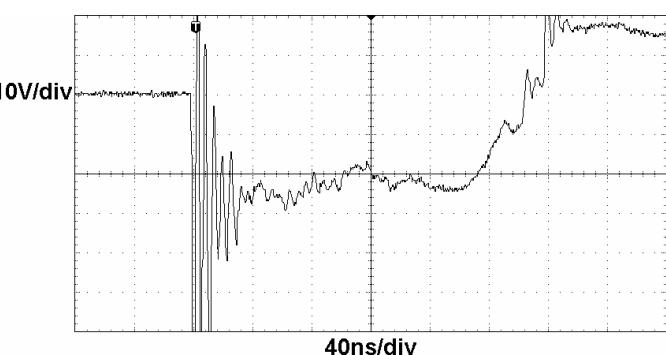
**Non-Repetitive Peak Pulse Power vs. Pulse time**



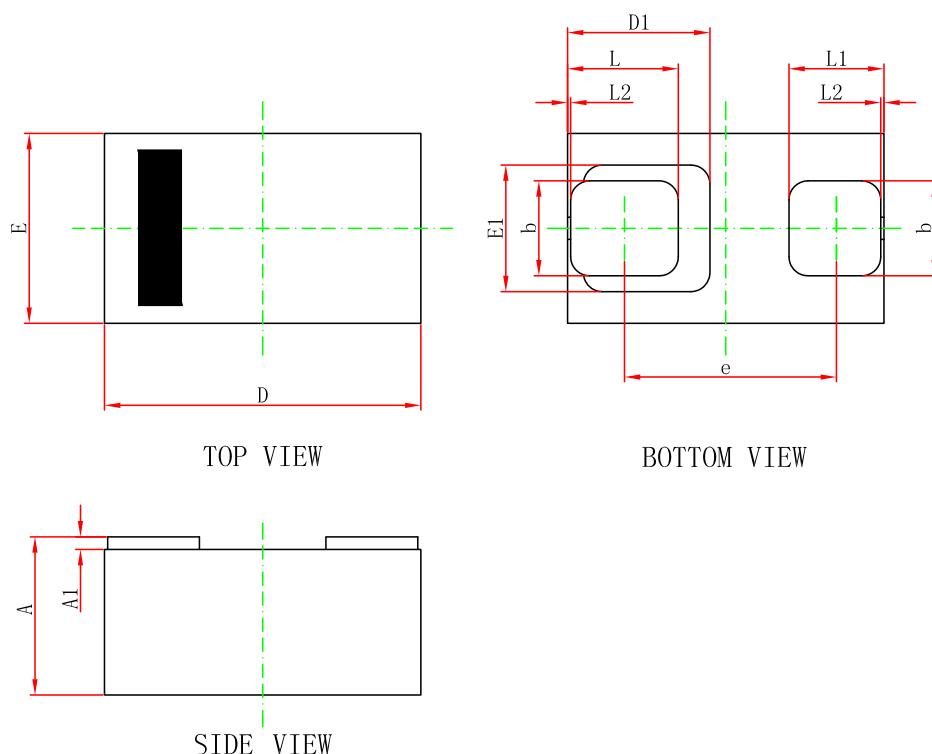
**Power derating vs. Temperature**



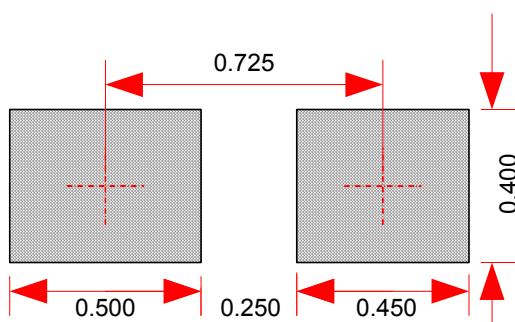
**ESD clamping voltage**  
(IEC61000-4-2 +8kV contact)

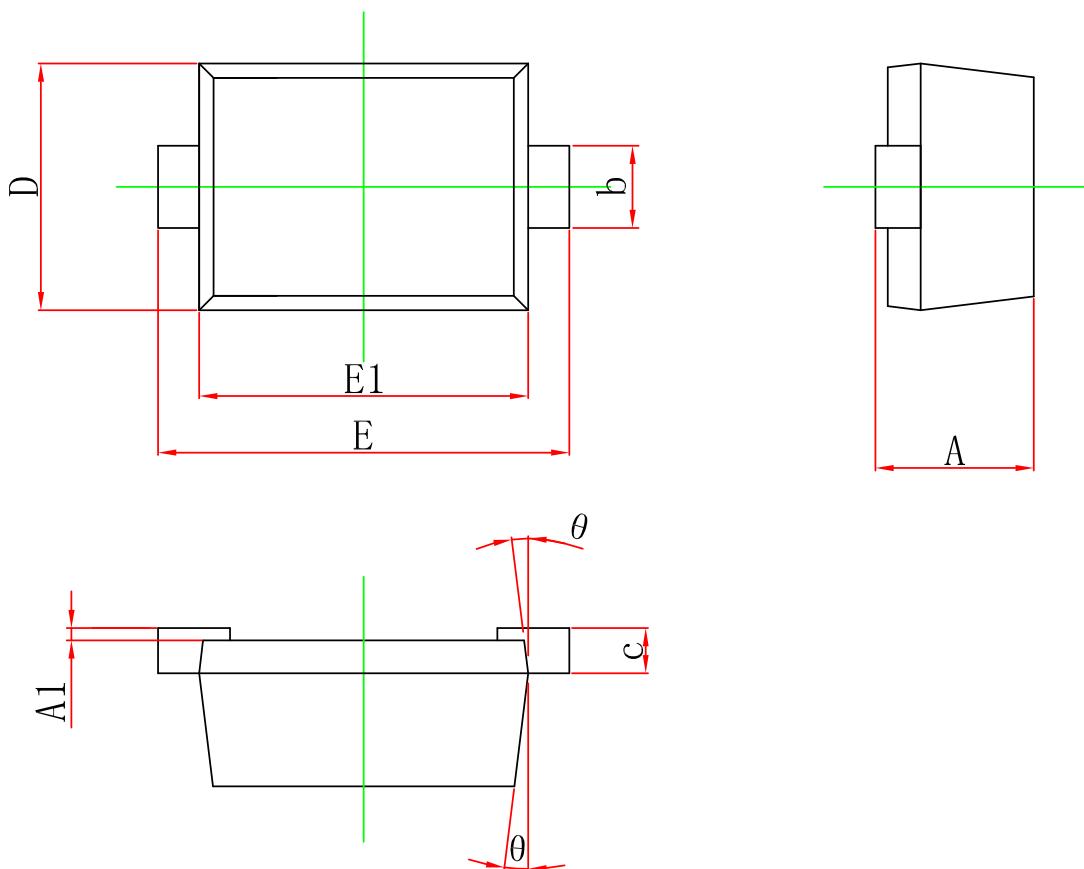


**ESD clamping voltage**  
(IEC61000-4-2 -8kV contact)

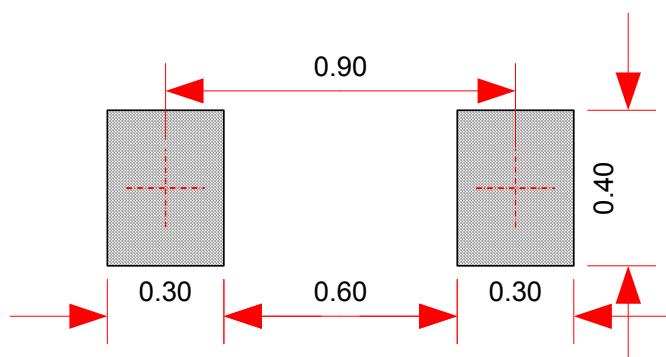
**Package outline dimensions****FBP-02C**

<b>Symbol</b>	<b>Dimensions in millimeter</b>		
	<b>Min.</b>	<b>Typ.</b>	<b>Max.</b>
A	0.450	0.500	0.550
A1	0.010	-	0.090
D	0.950	1.000	1.050
E	0.550	0.600	0.650
D1		0.450 Ref.	
E1		0.400 Ref.	
b	0.250	0.300	0.350
e	0.600	0.675	0.750
L	0.320	0.385	0.450
L1	0.250	0.300	0.350
L2		0.010 Ref.	

**Recommend PCB Layout (Unit: mm)**

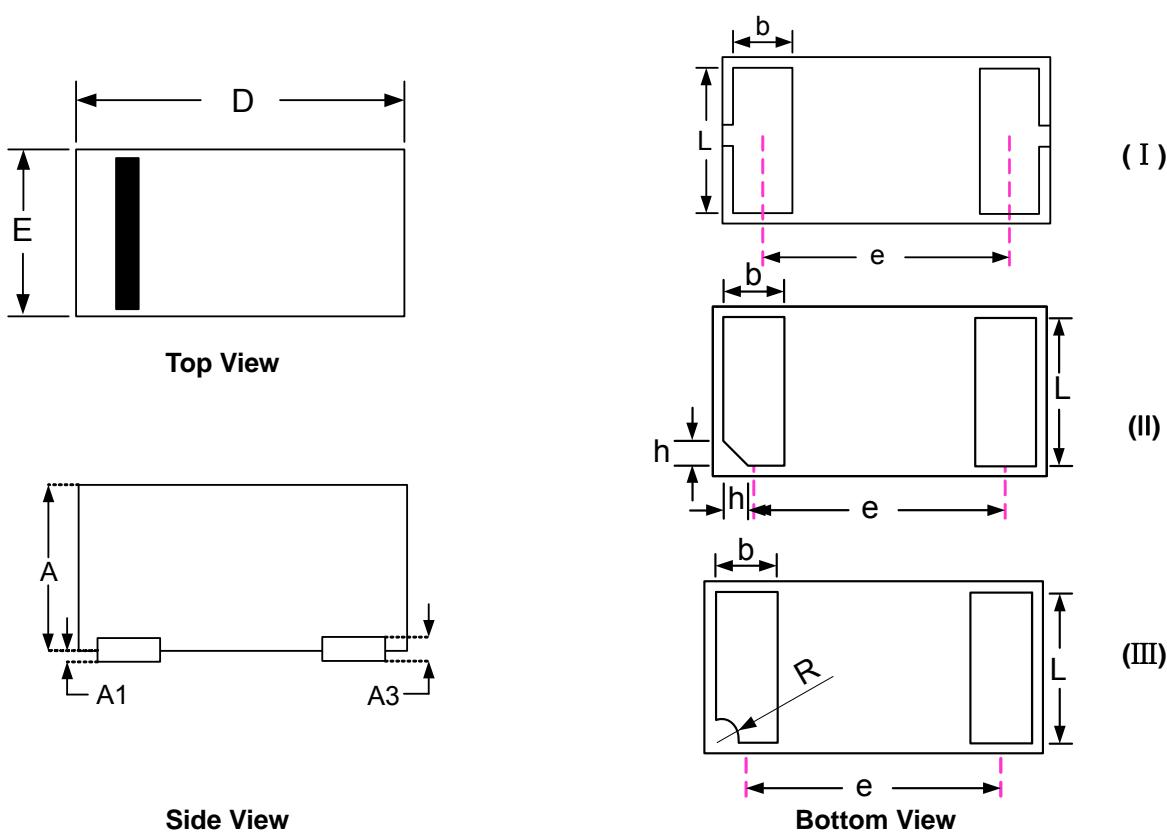
**Package outline dimensions****SOD-923**

Symbol	Dimensions in millimeter		
	Min.	Typ.	Max.
A	0.350	-	0.450
A1	0.000	-	0.050
b	0.150	-	0.270
c			0.180
D	0.550	0.600	0.650
E	0.900	1.000	1.100
E1	0.750	0.800	0.850
θ		7° Ref.	

**Recommend PCB Layout (Unit: mm)**

## Package outline dimensions

DFN1006-2L



Symbol	Dimensions in millimeter		
	Min.	Typ.	Max.
A	0.3	-	0.5
A1	0.00	-	0.05
A3	0.125 Ref.		
D	0.95	1.00	1.05
E	0.55	0.60	0.65
b	0.15	0.25	0.35
L	0.40	0.50	0.60
h	0.07	0.12	0.17
R	0.05	0.10	0.15
e	0.65 Typ.		

Recommend PCB Layout (Unit: mm)

